

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	675	((438/144,60,75,for.213).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/17 10:01
L2	0	((Junction near field near effect near transistor JFET) with (metal near oxide near silicon MOS MOSFET) with (bipolar)) and 1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/17 10:01
L3	868	((438/60,75,76,77,78,79,144,145,146,147,148,for.213).CCLS.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/17 10:03
L4	0	3 and transisstor with (amplify\$3 amplifi\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/17 10:05
L5	29	3 and transistor with (amplify\$3 amplifi\$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/17 10:05